

ABSTRACT

A semiconductor encapsulating epoxy resin composition
5 comprising (A) an epoxy resin, (B) a phenolic resin curing
agent, (C) a molybdenum compound, and (D) 300-900 parts by
weight per 100 parts by weight of components (A) and (B)
combined of an inorganic filler contains nitrogen atoms in
an amount of 1.5-20% by weight based on the weight of
10 components (A) and (B) combined. Cured parts of the
composition exhibit high-temperature capabilities and flame
retardance despite the absence of halogenated epoxy resins
and antimony trioxide.